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RENESAS TECHNICAL UPDATE

TOYOSU FORESIA, 3-2-24, Toyosu, Koto-ku, Tokyo 135-061, Japan
Renesas Electronics Corporation

Product Category	MPU/MCU	Document No.	TN-RA*-A0068A/E	Rev.	1.00
Title	Correction for “SPI Timing” in RA2L1/RA2E1/RA2E2 User’s Manual		Information Category	Technical Notification	
Applicable Product	RA Family RA2L1/RA2E1/RA2E2 Group	Lot No. All lots	Reference Document	Renesas RA2L1 Group User’s Manual: Hardware R01UH0853EJ0120 Rev.1.20 Renesas RA2E1 Group User’s Manual: Hardware R01UH0852EJ0120 Rev.1.20 Renesas RA2E2 Group User’s Manual: Hardware R01UH0919EJ0110 Rev.1.10	

The electrical characteristics of “RSPCK clock rise and fall time” in SPI Timing is changed.

The details are shown from the next page.

Group: RA2L1

Chapter 41.3.9 SPI Timing

Before）

Table 41.32 SPI timing (1 of 3)

Parameter				Symbol	Min	Max	Unit*1	Test conditions
SPI	RSPCK clock cycle	Master	2.7 V ≤ VCC ≤ 5.5 V	t_{SPcyc}	62.5	—	ns	Figure 41.28 C = 30 pF
			2.4 V ≤ VCC < 2.7 V		125	—		
			1.8 V ≤ VCC < 2.4 V		250	—		
			1.6 V ≤ VCC < 1.8 V		500	—		
		Slave	2.7 V ≤ VCC ≤ 5.5 V		187.5	—		
			2.4 V ≤ VCC < 2.7 V		375	—		
			1.8 V ≤ VCC < 2.4 V		750	—		
			1.6 V ≤ VCC < 1.8 V		1500	—		
	RSPCK clock high pulse width	Master		t_{SPCKWH}	(t_{SPcyc} - t_{SPCKr} - t_{SPCKf}) / 2 - 3	—	ns	
		Slave			3 × t_{Pcyc}	—		
	RSPCK clock low pulse width	Master		t_{SPCKWL}	(t_{SPcyc} - t_{SPCKr} - t_{SPCKf}) / 2 - 3	—	ns	
		Slave			3 × t_{Pcyc}	—		
	RSPCK clock rise and fall time	Output	2.7 V ≤ VCC ≤ 5.5 V	t_{SPCKr}, t_{SPCKf}	—	10	ns	
			2.4 V ≤ VCC < 2.7 V		—	15		
			1.8 V ≤ VCC ≤ 2.4 V		—	20		
			1.6 V ≤ VCC < 1.8 V		—	30		
		Input			—	1	μs	

After）

The input characteristic of “RSPCK clock rise and fall time” is changed as below in Table 41.32.

Max value and unit are changed to 0.1 μs/V from previous 1 μs.

Table 41.32 SPI timing (1 of 3)

Parameter				Symbol	Min	Max	Unit*1	Test conditions
SPI	RSPCK clock cycle	Master	2.7 V ≤ VCC ≤ 5.5 V	t_{SPcyc}	62.5	—	ns	Figure 41.28 C = 30 pF
			2.4 V ≤ VCC < 2.7 V		125	—		
			1.8 V ≤ VCC < 2.4 V		250	—		
			1.6 V ≤ VCC < 1.8 V		500	—		
		Slave	2.7 V ≤ VCC ≤ 5.5 V		187.5	—		
			2.4 V ≤ VCC < 2.7 V		375	—		
			1.8 V ≤ VCC < 2.4 V		750	—		
			1.6 V ≤ VCC < 1.8 V		1500	—		
	RSPCK clock high pulse width	Master		t_{SPCKWH}	(t_{SPcyc} - t_{SPCKr} - t_{SPCKf}) / 2 - 3	—	ns	
		Slave			3 × t_{Pcyc}	—		
	RSPCK clock low pulse width	Master		t_{SPCKWL}	(t_{SPcyc} - t_{SPCKr} - t_{SPCKf}) / 2 - 3	—	ns	
		Slave			3 × t_{Pcyc}	—		
	RSPCK clock rise and fall time	Output	2.7 V ≤ VCC ≤ 5.5 V	t_{SPCKr}, t_{SPCKf}	—	10	ns	
			2.4 V ≤ VCC < 2.7 V		—	15		
			1.8 V ≤ VCC ≤ 2.4 V		—	20		
			1.6 V ≤ VCC < 1.8 V		—	30		
		Input			—	0.1	μs/V	

Group: RA2E1

Chapter 39.3.9 SPI Timing

Before）

Table 39.32 SPI timing (1 of 3)

Parameter				Symbol	Min	Max	Unit*1	Test conditions
SPI	RSPCK clock cycle	Master	2.7 V ≤ VCC ≤ 5.5 V	t_{SPcyc}	62.5	—	ns	Figure 39.28 C = 30 pF
			2.4 V ≤ VCC < 2.7 V		125	—		
			1.8 V ≤ VCC < 2.4 V		250	—		
			1.6 V ≤ VCC < 1.8 V		500	—		
		Slave	2.7 V ≤ VCC ≤ 5.5 V		187.5	—		
			2.4 V ≤ VCC < 2.7 V		375	—		
			1.8 V ≤ VCC < 2.4 V		750	—		
			1.6 V ≤ VCC < 1.8 V		1500	—		
	RSPCK clock high pulse width	Master		t_{SPCKWH}	(t_{SPcyc} - t_{SPCKr} - t_{SPCKf}) / 2 - 3	—	ns	
		Slave			3 × t_{Pcyc}	—		
	RSPCK clock low pulse width	Master		t_{SPCKWL}	(t_{SPcyc} - t_{SPCKr} - t_{SPCKf}) / 2 - 3	—	ns	
		Slave			3 × t_{Pcyc}	—		
	RSPCK clock rise and fall time	Output	2.7 V ≤ VCC ≤ 5.5 V	t_{SPCKr}, t_{SPCKf}	—	10	ns	
			2.4 V ≤ VCC < 2.7 V		—	15		
			1.8 V ≤ VCC ≤ 2.4 V		—	20		
			1.6 V ≤ VCC < 1.8 V		—	30		
		Input			—	1	μs	

After）

The input characteristic of “RSPCK clock rise and fall time” is changed as below in Table 39.32.

Max value and unit are changed to 0.1 μs/V from previous 1 μs.

Table 39.32 SPI timing (1 of 3)

Parameter				Symbol	Min	Max	Unit*1	Test conditions
SPI	RSPCK clock cycle	Master	2.7 V ≤ VCC ≤ 5.5 V	t_{SPcyc}	62.5	—	ns	Figure 39.28 C = 30 pF
			2.4 V ≤ VCC < 2.7 V		125	—		
			1.8 V ≤ VCC < 2.4 V		250	—		
			1.6 V ≤ VCC < 1.8 V		500	—		
		Slave	2.7 V ≤ VCC ≤ 5.5 V		187.5	—		
			2.4 V ≤ VCC < 2.7 V		375	—		
			1.8 V ≤ VCC < 2.4 V		750	—		
			1.6 V ≤ VCC < 1.8 V		1500	—		
	RSPCK clock high pulse width	Master		t_{SPCKWH}	(t_{SPcyc} - t_{SPCKr} - t_{SPCKf}) / 2 - 3	—	ns	
		Slave			3 × t_{Pcyc}	—		
	RSPCK clock low pulse width	Master		t_{SPCKWL}	(t_{SPcyc} - t_{SPCKr} - t_{SPCKf}) / 2 - 3	—	ns	
		Slave			3 × t_{Pcyc}	—		
	RSPCK clock rise and fall time	Output	2.7 V ≤ VCC ≤ 5.5 V	t_{SPCKr}, t_{SPCKf}	—	10	ns	
			2.4 V ≤ VCC < 2.7 V		—	15		
			1.8 V ≤ VCC ≤ 2.4 V		—	20		
			1.6 V ≤ VCC < 1.8 V		—	30		
		Input			—	0.1	μs/V	

Group: RA2E2

Chapter 36.3.9 SPI Timing

Before）

Table 36.32 SPI timing (1 of 3)

Parameter				Symbol	Min	Max	Unit*1	Test conditions
SPI	RSPCK clock cycle	Master	2.7 V ≤ VCC ≤ 5.5 V	t_{SPcyc}	62.5	—	ns	Figure 36.26 C = 30 pF
			2.4 V ≤ VCC < 2.7 V		125	—		
			1.8 V ≤ VCC < 2.4 V		250	—		
			1.6 V ≤ VCC < 1.8 V		500	—		
		Slave	2.7 V ≤ VCC ≤ 5.5 V		187.5	—		
			2.4 V ≤ VCC < 2.7 V		375	—		
			1.8 V ≤ VCC < 2.4 V		750	—		
			1.6 V ≤ VCC < 1.8 V		1500	—		
	RSPCK clock high pulse width	Master		t_{SPCKWH}	(t_{SPcyc} - t_{SPCKr} - t_{SPCKf}) / 2 - 3	—	ns	
		Slave			3 × t_{Pcyc}	—		
	RSPCK clock low pulse width	Master		t_{SPCKWL}	(t_{SPcyc} - t_{SPCKr} - t_{SPCKf}) / 2 - 3	—	ns	
		Slave			3 × t_{Pcyc}	—		
	RSPCK clock rise and fall time	Output	2.7 V ≤ VCC ≤ 5.5 V	t_{SPCKr}, t_{SPCKf}	—	10	ns	
			2.4 V ≤ VCC < 2.7 V		—	15		
			1.8 V ≤ VCC ≤ 2.4 V		—	20		
			1.6 V ≤ VCC < 1.8 V		—	30		
		Input			—	1	μs	

After）

The input characteristic of “RSPCK clock rise and fall time” is changed as below in Table 36.32.

Max value and unit are changed to 0.1 μs/V from previous 1 μs.

Table 36.32 SPI timing (1 of 3)

Parameter				Symbol	Min	Max	Unit*1	Test conditions
SPI	RSPCK clock cycle	Master	2.7 V ≤ VCC ≤ 5.5 V	t_{SPcyc}	62.5	—	ns	Figure 36.26 C = 30 pF
			2.4 V ≤ VCC < 2.7 V		125	—		
			1.8 V ≤ VCC < 2.4 V		250	—		
			1.6 V ≤ VCC < 1.8 V		500	—		
		Slave	2.7 V ≤ VCC ≤ 5.5 V		187.5	—		
			2.4 V ≤ VCC < 2.7 V		375	—		
			1.8 V ≤ VCC < 2.4 V		750	—		
			1.6 V ≤ VCC < 1.8 V		1500	—		
	RSPCK clock high pulse width	Master		t_{SPCKWH}	(t_{SPcyc} - t_{SPCKr} - t_{SPCKf}) / 2 - 3	—	ns	
		Slave			3 × t_{Pcyc}	—		
	RSPCK clock low pulse width	Master		t_{SPCKWL}	(t_{SPcyc} - t_{SPCKr} - t_{SPCKf}) / 2 - 3	—	ns	
		Slave			3 × t_{Pcyc}	—		
	RSPCK clock rise and fall time	Output	2.7 V ≤ VCC ≤ 5.5 V	t_{SPCKr}, t_{SPCKf}	—	10	ns	
			2.4 V ≤ VCC < 2.7 V		—	15		
			1.8 V ≤ VCC ≤ 2.4 V		—	20		
			1.6 V ≤ VCC < 1.8 V		—	30		
		Input			—	0.1	μs/V	